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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/708,748	03/23/2004	Wei Lu	FIS920030308	2747
29154	7590 08/23/2005		EXAMINER	
FREDERICK W. GIBB, III			JOHNSTON, PHILLIP A	
MCGINN &	GIBB, PLLC			
2568-A RIV	A ROAD		ART UNIT	PAPER NUMBER
SUITE 304			2881	
ANNAPOLIS	S, MD 21401		DATE MAILED: 08/23/2005	

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)	
	10/708,748	LU ET AL.	
Office Action Summary	Examiner	Art Unit	
	Phillip A. Johnston	2881	
The MAILING DATE of this communication ap Period for Reply	pears on the cover sheet with	the correspondence address	
A SHORTENED STATUTORY PERIOD FOR REPL THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1, after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a reply In NO period for reply is specified above, the maximum statutory period and the period for reply within the set or extended period for reply will, by statut any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).	. 136(a). In no event, however, may a repley within the statutory minimum of thirty (and will expire SIX (6) MONTHE te, cause the application to become ABAN	y be timely filed 30) days will be considered timely. IS from the mailing date of this communication. IDONED (35 U.S.C. § 133).	
Status			
1) Responsive to communication(s) filed on 13	September 2004.		
2a) ☐ This action is FINAL . 2b) ☑ Thi	is action is non-final.		
3) Since this application is in condition for allowated closed in accordance with the practice under		•	
Disposition of Claims			
 4) Claim(s) 1-20 is/are pending in the application 4a) Of the above claim(s) is/are withdrays. 5) Claim(s) is/are allowed. 6) Claim(s) 1-20 is/are rejected. 7) Claim(s) is/are objected to. 8) Claim(s) are subject to restriction and/ 	awn from consideration.		
Application Papers			
9) ☐ The specification is objected to by the Examin 10) ☑ The drawing(s) filed on 23 March 2004 is/are: Applicant may not request that any objection to the Replacement drawing sheet(s) including the correct 11) ☐ The oath or declaration is objected to by the Examin 11.	a) accepted or b) objected or awing(s) objection is required if the drawing(s)	e. See 37 CFR 1.85(a). is objected to. See 37 CFR 1.121(d).	
Priority under 35 U.S.C. § 119			
12) Acknowledgment is made of a claim for foreig a) All b) Some * c) None of: 1. Certified copies of the priority documer 2. Certified copies of the priority documer 3. Copies of the certified copies of the priority application from the International Burea * See the attached detailed Office action for a list	nts have been received. Ints have been received in Appointly documents have been read au (PCT Rule 17.2(a)).	olication No eceived in this National Stage	
Attachment(s)	-		
 Notice of References Cited (PTO-892) Notice of Draftsperson's Patent Drawing Review (PTO-948) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08 Paper No(s)/Mail Date 3-23-2004. 		Mail Date rmal Patent Application (PTO-152)	

Detailed Action

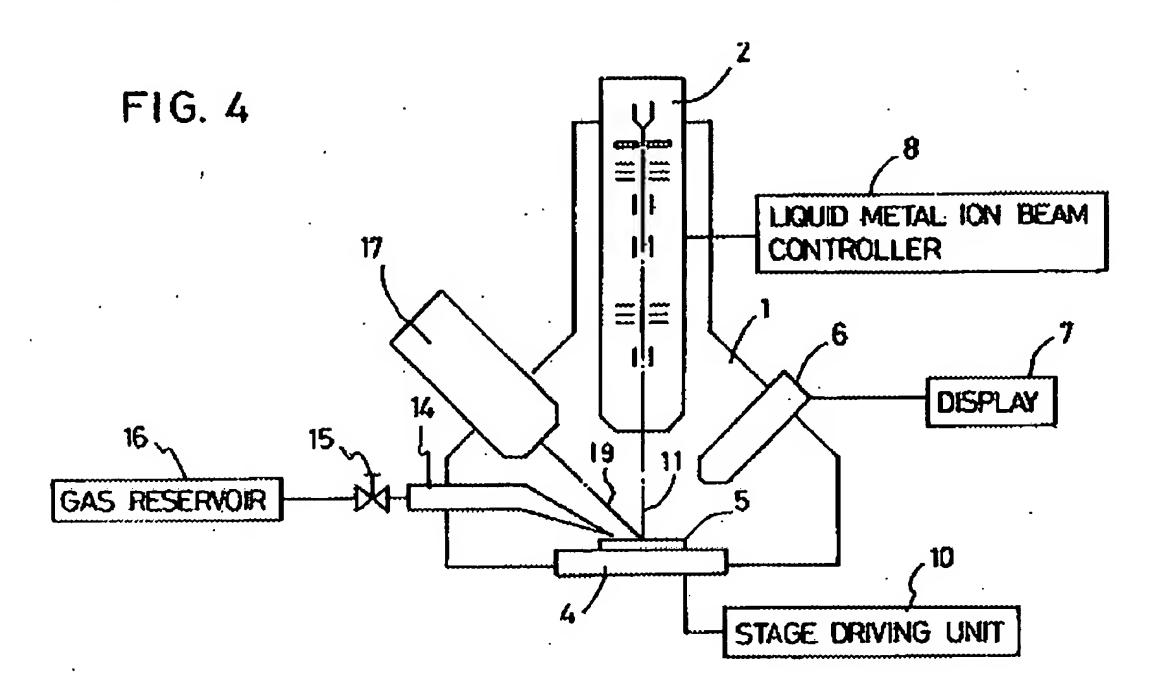
Claims Rejection - 35 U.S. C. 102

- 1. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:
 - (b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.
 - 2. Claims 1-5,8-12, and 15-18 are rejected under 35 U.S.C. 102 (b) as being clearly anticipated by Fujii, U. S. Patent No. 5,574,280.

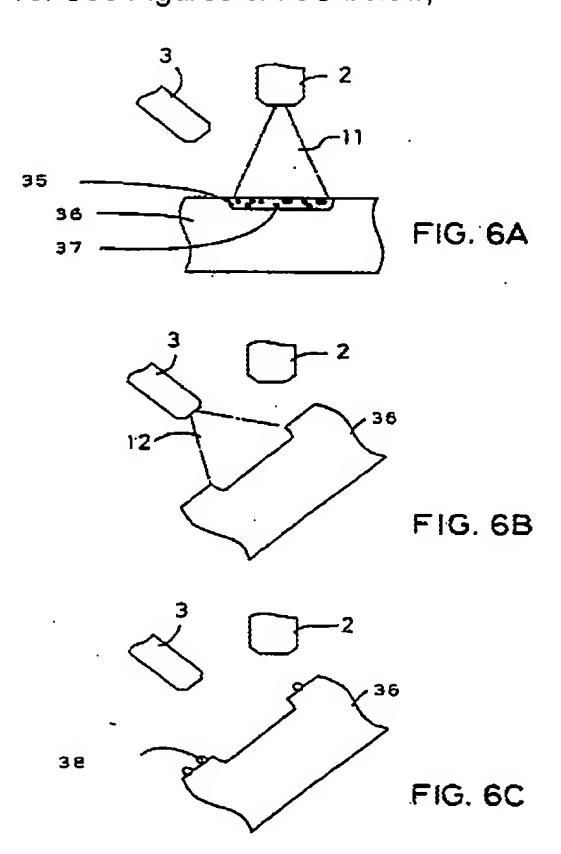
Fujii (280) discloses the following;

(a) Use of electron beam irradiation unit 17 to irradiate hexacarbonyl tungsten gas (organic metal gas) blown by the organic gas source 14 onto the surface of semiconductor device 5, and while irradiated with the energy beam source 17 a tungsten film is formed on the surface. A portion of the sample 5 at the predetermined area is removed (forms a groove) by ion beam sputtering, exposing the cross-section (e.g. wiring at the boundary) of the semiconductor. Subsequent irradiation at the section with the focused ion beam generates secondary particles, which are detected by a detector 6, and then the image of the section is displayed on the display 7 (inspecting the exposed area), as recited in claims 1,8, and 15. See Column 2, line 40-49; Column 4, line 34-45; Column 5, line 47-57; and Figure 4 below;

Art Unit: 2881



(b) The use of a tilted stage shown in Figures 6A-6C; as recited in claims 2,3, and 10. See Figures 6A-6C below;



Art Unit: 2881

It is implied herein that, secondary electrons are generated when electron beam source 17 irradiates semiconductor sample 5, and these generated secondary electrons, along with the primary beam electrons, contribute to the dissociation (breakdown) of the organic gas, which results in deposition of the metal coating onto the semiconductor surface, as recited in claims 4,11, and 15.

It is also implied herein that, secondary electrons always have less energy than the primary electrons that generate them, as recited in claims 5 and 12.

Claims Rejection - 35 U.S.C. 103

- 3. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
- (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which the subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 4. Claims 7,14, and 20 are rejected under 35 U.S.C. 103(a) as being unpatentable over U.S. Patent No. 5,574,280 to Fujii, in view of Berger, U.S. Patent Pub. No. 20040065826.

Fujii (280) as described above discloses nearly all the limitations of claims 7,14, and 20 but fails to teach the use of an incident electron beam angle between 20 and 70 degrees relative to the sample surface. However Berger (826) discloses a particle-beam system 10 for obtaining an image of a cross-section of a workpiece 11, as

Application/Control Number: 10/708,748

Art Unit: 2881

shown in FIG. 1, includes a shaped-beam ion-projection column 12 configured to project an image of an aperture onto the front surface 14 of the workpiece 11, and further includes a focused-particle-beam imaging column 20, which is an electron beam provided by a scanning electron microscope. The column 20 is oriented along a second axis 22 that is canted relative to the first axis 18 so that it intersects the first axis 18 at a selected angle. The selected angle is preferably between thirty and sixty degrees, as recited in claims 7,14, and 20. See paragraph's [0024], [0025]; [0039]; and Figure 1 below;

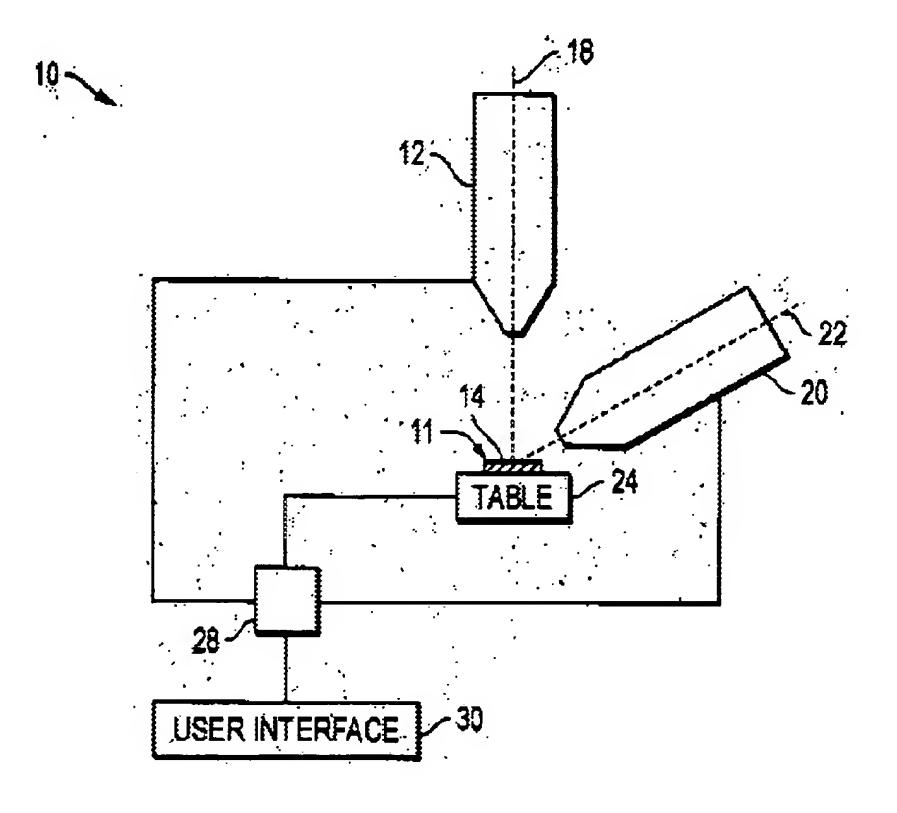


FIG. 1

Application/Control Number: 10/708,748

Art Unit: 2881

Therefore it would have been obvious to one of ordinary skill in the art that the ion beam apparatus and method of Fujii (280) can be modified to use the incident electron beam angles specified in the apparatus and method of Berger (826), to provide a method and system for imaging a cross-section of a substrate that is capable of switching from a cutting mode to an imaging mode in order to view the vertical wall of the excavated cross-section.

5. Claims 6,13, and 19 are rejected under 35 U.S.C. 103(a) as being unpatentable over U.S. Patent No. 5,574,280 to Fujii, in view of Christy, U.S. Patent No. 3,119,707.

Fujii (280) as described above discloses nearly all the limitations of claims 6,13, and 19, but fails to teach the use of electron beams having energy levels between 100 and 10,000 electron volts to form a metal film. However, Christy (707) discloses a method for deposition of thin films that includes the use of a substrate located within an evacuated chamber, that is enveloped with the vapor molecules of a metal-organic compound, which is irradiated with a beam of electrons accelerated at 225 volts, whereby a metal film is formed as the vapor molecules adsorbed on the substrate are decomposed by the electron beam, as recited in claims 6,13, and 19. See Column 2, line 24-32; and Column 4, line 27-40.

Therefore it would have been obvious to one of ordinary skill in the art that the ion beam apparatus and method of Fujii (280) can be modified with the accelerating potentials in the apparatus and method of Christy (707), to provide a beam of

Application/Control Number: 10/708,748

Art Unit: 2881

Page 7

substrate.

Conclusion

6. Any inquiry concerning this communication or earlier communications should be

directed to Phillip Johnston whose telephone number is (571) 272-2475. The examiner

electrons directed against a vapor of metal organic molecules to form a metal film on a

can normally be reached on Monday-Friday from 7:30 am to 4:00 pm. If attempts to

reach the examiner by telephone are unsuccessful, the examiners supervisor John Lee

can be reached at (571) 272-2477. The fax phone number for the organization where

the application or proceeding is assigned is 703 872 9306.

Information regarding the status of an application may be obtained from the

Patent Application Information Retrieval (PAIR) system. Status information for

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you have questions on access to the Private PAIR system, contact the Electronic

Business Center (EBC) at 866-217-9197 (toll-free).

PJ

August 20, 2005

JOHN R. LEE

SUPERVISORY PATENT EXAMINER

TECHNOLOGY CENTER 2600